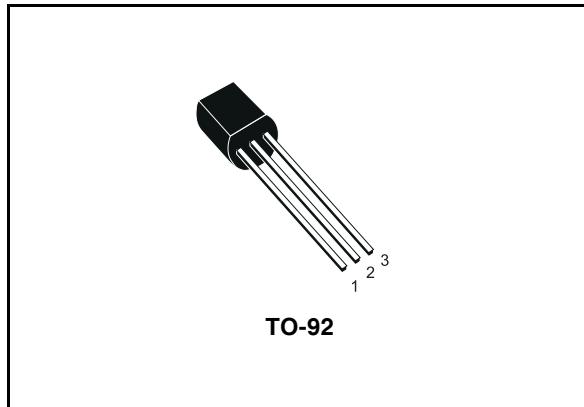


General features

- Very low Collector to Emitter saturation voltage
- D.C. Current gain, $h_{FE} > 100$
- 1.5 A continuous collector current
- In compliance with the 2002/93/EC European Directive

Description

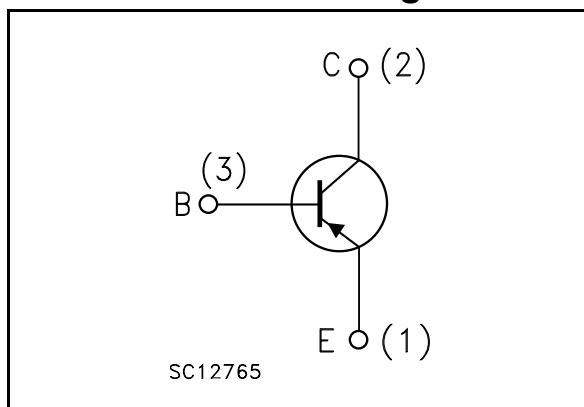
The device is a PNP transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.



Applications

- Power management in portable equipment
- Switching regulator in battery charger applications

Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
2STX2220	X2220	TO-92	Bulk

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1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage ($I_E = 0$)	-20	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	-20	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	-5	V
I_C	Collector current	-1.5	A
I_{CM}	Collector peak current ($t_P < 5\text{ms}$)	-3	A
I_B	Base current	-0.1	A
I_{BM}	Base peak current ($t_P < 5\text{ms}$)	-0.2	A
P_{tot}	Total dissipation at $T_{amb} = 25^\circ\text{C}$	0.9	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case	max	44.6
$R_{thj-amb}$	Thermal resistance junction-amb	max	139

2 Electrical characteristics

($T_{case} = 25^\circ\text{C}$ unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_E = 0$)	$V_{CB} = -20\text{V}$			-0.1	μA
I_{EBO}	Emitter cut-off current ($I_C = 0$)	$V_{EB} = -5\text{V}$			-0.1	μA
$V_{(BR)CEO}^{(2)}$	Collector-emitter breakdown voltage ($I_B = 0$)	$I_C = -10\text{mA}$	-20			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage ($I_C = 0$)	$I_E = -100\mu\text{A}$	-5			V
$V_{CE(sat)}^{(2)}$	Collector-emitter saturation voltage	$I_C = -0.5\text{A} \quad I_B = -50\text{mA}$ $I_C = -1.5\text{A} \quad I_B = -150\text{mA}$			-0.25 -0.45	V
$V_{BE(sat)}^{(2)}$	Base-emitter saturation voltage	$I_C = -0.5\text{A} \quad I_B = -50\text{mA}$ $I_C = -1.5\text{A} \quad I_B = -150\text{mA}$			-1 -1.1	V
$V_{BE(on)}^{(2)}$	Base-emitter on voltage	$I_C = -1\text{A} \quad V_{CE} = -2\text{V}$			-1	V
$h_{FE}^{(2)}$	DC current gain	$I_C = -100\text{mA} \quad V_{CE} = -2\text{V}$ $I_C = -500\text{mA} \quad V_{CE} = -2\text{V}$ $I_C = -1.5\text{A} \quad V_{CE} = -2\text{V}$ $I_C = -3\text{A} \quad V_{CE} = -2\text{V}$	200 170 120 75		600	
C_{CBO}	Collector-base capacitance	$I_E = 0 \quad V_{CB} = -10\text{V}$ $f = 1\text{MHz}$		30		pF
t_{on} t_{off}	Resistive load Turn-on time Turn-off time	$I_C = -1.5\text{A} \quad V_{CC} = -10\text{V}$ $I_{B1} = -I_{B2} = -150\text{mA}$		60 250		ns ns

Note (2) Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 1. Output characteristics

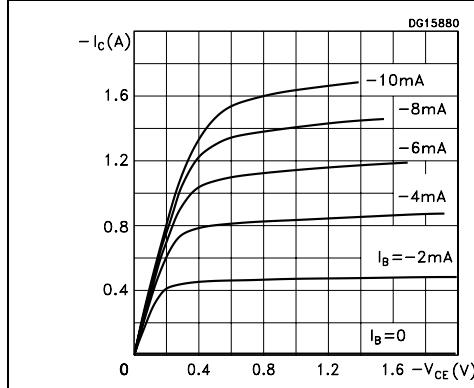


Figure 2. DC current gain

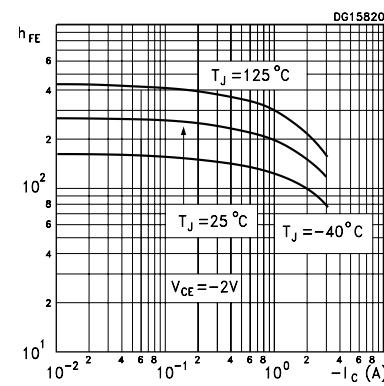


Figure 3. DC current gain

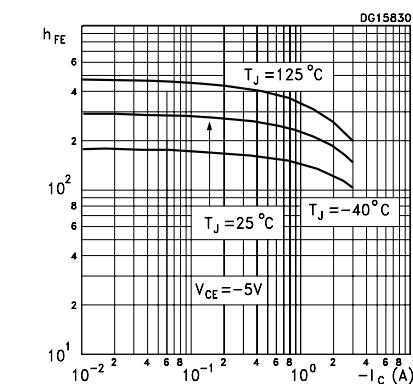


Figure 4. Collector-emitter saturation voltage

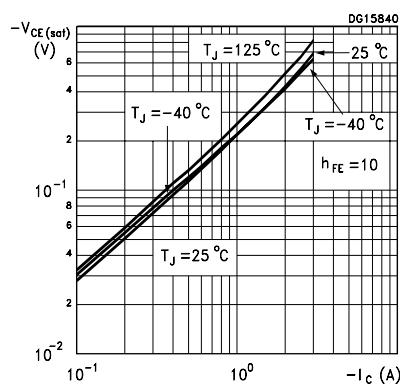


Figure 5. Base-emitter saturation voltage

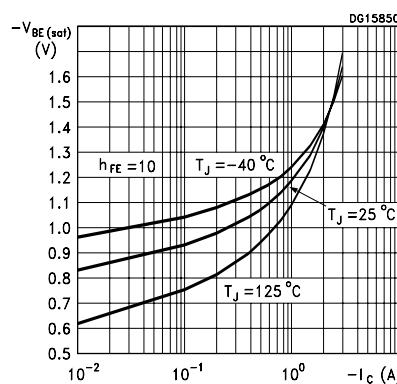


Figure 6. Base-emitter on voltage

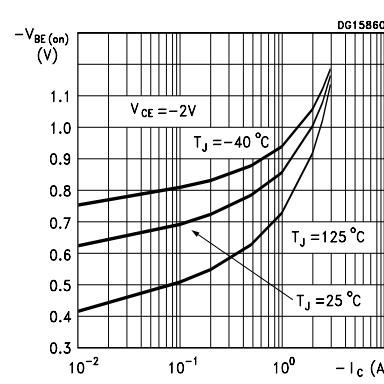
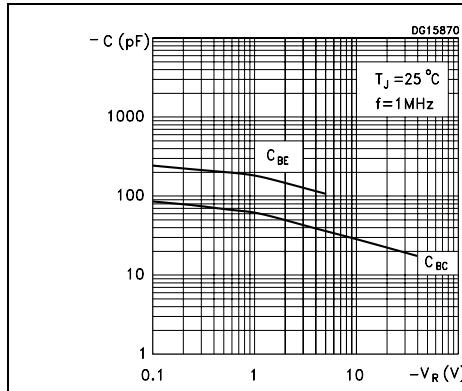
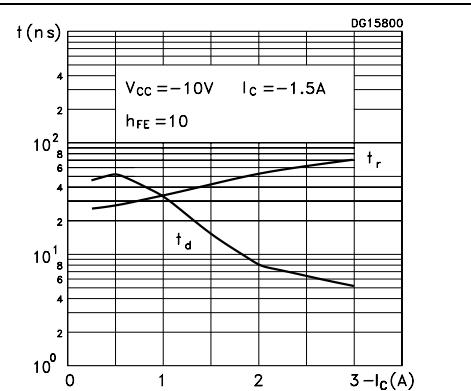
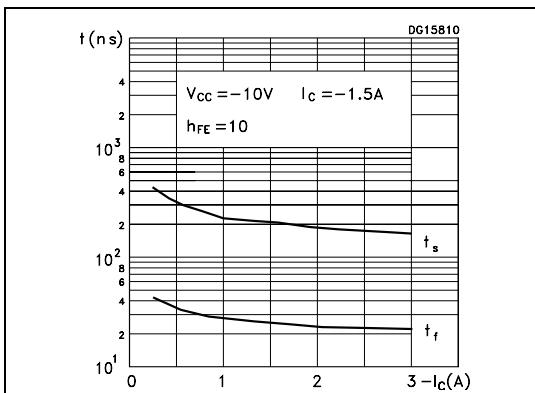
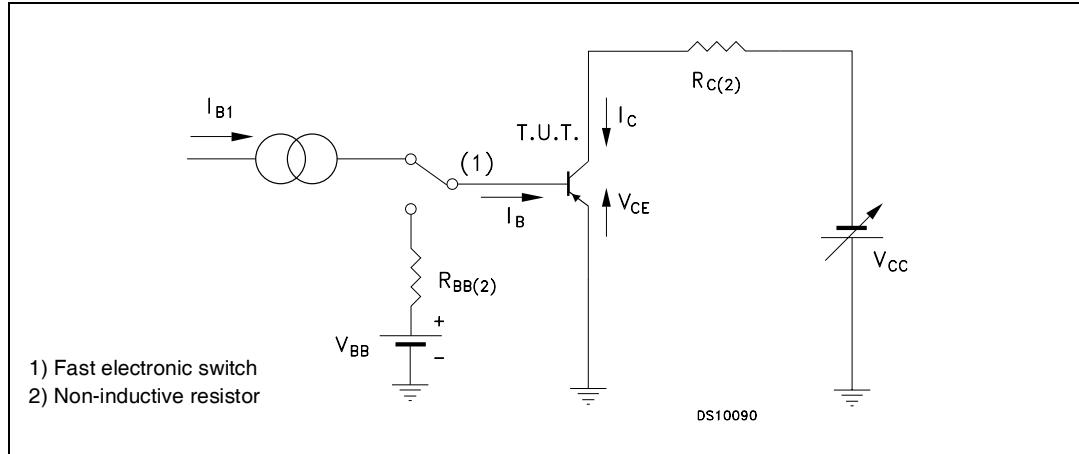


Figure 7. Capacitance curves**Figure 8. Switching time resistive load****Figure 9. Switching time resistive load**

2.2 Test circuits

Figure 10. Resistive load switching test circuit

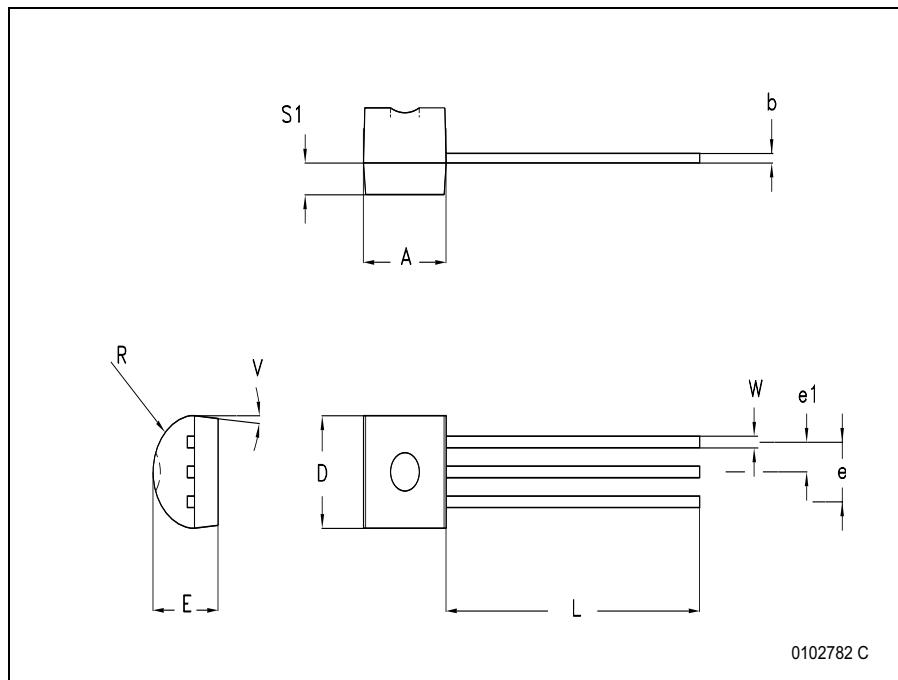


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-92 BULK SHIPMENT MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5°	



4 Revision history

Table 4. Revision history

Date	Revision	Changes
19-Jun-2006	1	Initial release.
25-Sep-2006	2	New maturity code.

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